

Features

- $BV_{CEO} > -60V$
- $BV_{EBO} > -8V$
- Continuous Current I_C to -6A
- Peak Pulse Current I_{CM} to -12A
- Ultra-Low Saturation Voltage $V_{CE(sat)} < -50mV @ -1A$
- High Current $R_{CE(sat)} = 26m\Omega$ Typical
- Small Form Factor Thermally Efficient Package Enables Higher Density End Products
- Wettable Flank for Improved Optical Inspection
- Rated to +175°C – Ideal for High-Temperature Environments
- Complementary NPN Type: DXTN80060DFGQ
- **Lead-Free Finish; RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. “Green” Device (Note 3)**
- **The DXTP80060DFGQ is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.**
<https://www.diodes.com/quality/product-definitions/>

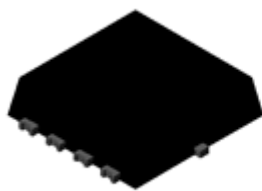
Mechanical Data

- Package: PowerDI[®]3333-8
- Package Material: Molded Plastic. “Green” Molding Compound. UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish - Matte Tin. Solderable per MIL-STD-202, Method 208 (A3)
- Weight: 0.03 grams (Approximate)

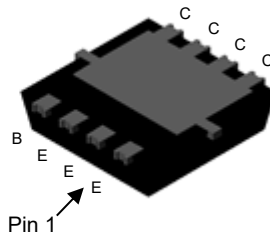
Applications

- MOSFET & IGBT gate drivers
- Load switches
- Low-voltage regulation
- DC to DC converters
- Motors, solenoids, relays and actuator drivers controls

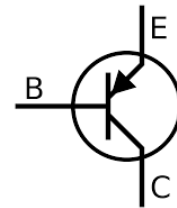
PowerDI3333-8/SWP (Type UX)



Top View



Bottom View



Device Symbol

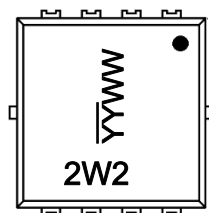
Ordering Information (Note 4)

| Orderable Part Number | Package | Marking | Reel Size (inches) | Tape Width (mm) | Packing | |
|-----------------------|-----------------------------|---------|--------------------|-----------------|---------|---------|
| | | | | | Qty. | Carrier |
| DXTP80060DFGQ-7 | PowerDI3333-8/SWP (Type UX) | 2W2 | 7 | 12 | 2,000 | Reel |

- Notes:
1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
 2. See <https://www.diodes.com/quality/lead-free/> for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
 4. For packaging details, go to our website at <https://www.diodes.com/design/support/packaging/diodes-packaging/>.

Marking Information

PowerDI3333-8/SWP (Type UX)



2W2 = Product Type Marking Code
 YYWW = Date Code Marking
 YY = Last Two Digits of Year (ex: 25 = 2025)
 WW = Week Code (01 to 53)

PowerDI is a registered trademark of Diodes Incorporated in the United States and other countries.

Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Value | Unit |
|---------------------------------------|------------------|-------|------|
| Collector-Base Voltage | V _{CBO} | -70 | V |
| Collector-Emitter Voltage | V _{CEO} | -60 | V |
| Emitter-Base Voltage | V _{EBO} | -8 | V |
| Continuous Collector Current (Note 5) | I _C | -3.5 | A |
| Continuous Collector Current (Note 7) | I _C | -6 | A |
| Peak Pulse Current | I _{CM} | -12 | A |

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Value | Unit |
|--|-----------------------------------|-------------|------|
| Power Dissipation | P _D | 900 | mW |
| | | 1.6 | W |
| | | 2.4 | W |
| Thermal Resistance, Junction to Ambient | R _{θJA} | 140 | °C/W |
| | | 92 | °C/W |
| | | 62.5 | °C/W |
| Thermal Resistance, Junction to Case (Note 7) | R _{θJC} | 6.5 | °C/W |
| Thermal Resistance, Junction to Leads (Note 8) | R _{θJL} | 4.2 | °C/W |
| Operating and Storage Temperature Range | T _J , T _{STG} | -55 to +175 | °C |

ESD Ratings (Note 9)

| Characteristic | Symbol | Value | Unit | JEDEC Class |
|--|---------|-------|------|-------------|
| Electrostatic Discharge - Human Body Model | ESD HBM | 4,000 | V | 3A |
| Electrostatic Discharge - Machine Model | ESD MM | 400 | V | C |
| Electrostatic Discharge - Charged Device Model | ESD CDM | 1,000 | V | IV |

- Notes:
5. For a device mounted with the collector tab on MRP FR4-PCB; device is measured under still air conditions whilst operating in a steady state.
 6. Same as Note 5, except the device is mounted on 15mm x 15mm 2oz copper.
 7. Same as Note 5, except the device is mounted on 25mm x 25mm 2oz copper.
 8. Thermal resistance from junction to solder-point (at the collector tab).
 9. Refer to JEDEC specifications JESD22-A114, JESD22-A115 and JESD22-C101.

Thermal Characteristics and Derating Information

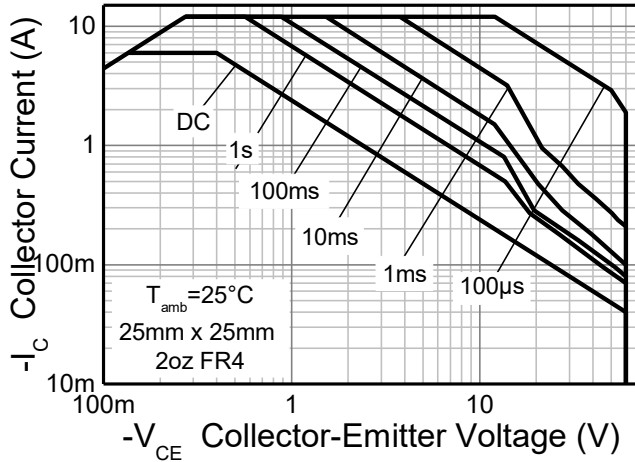


Fig 1. Safe Operating Area

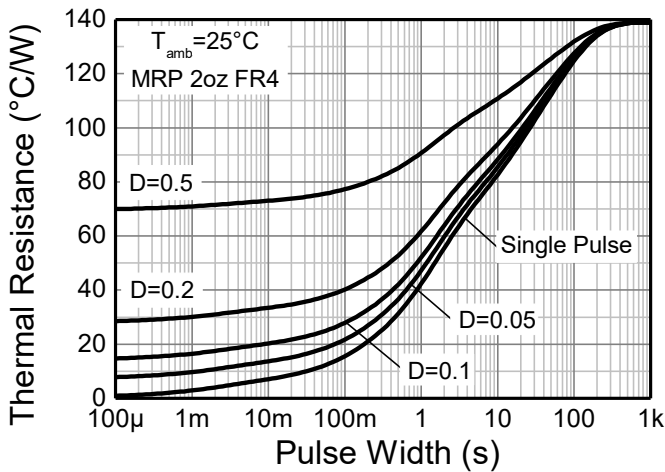


Fig 2. Transient Thermal Impedance

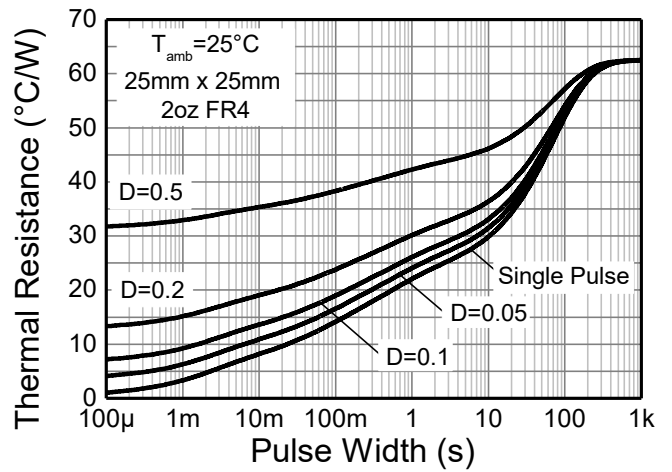


Fig 3. Transient Thermal Impedance

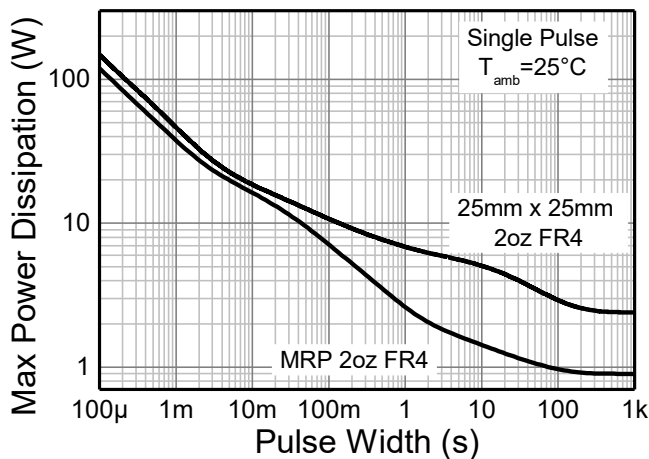


Fig 4. Pulse Power Dissipation

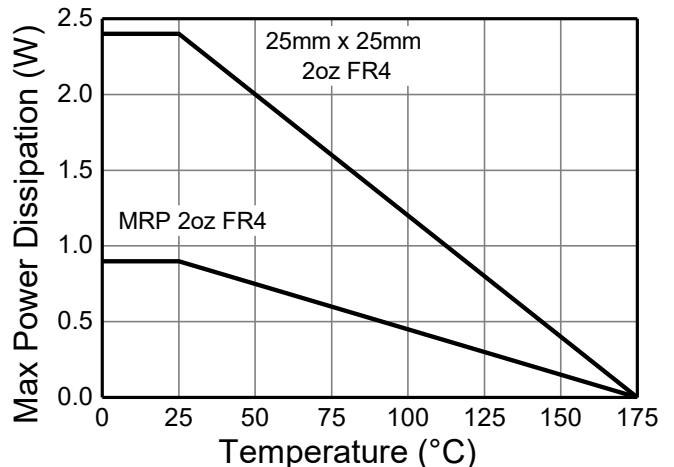


Fig 5. Derating Curve

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Min | Typ | Max | Unit | Test Condition |
|--|----------------------|-----|------|--------|------|---|
| Collector-Base Breakdown Voltage | BV _{CB0} | -70 | — | — | V | I _C = -100μA |
| Collector-Emitter Breakdown Voltage (Note 10) | BV _{CEO} | -60 | — | — | V | I _C = -10mA |
| Emitter-Collector Breakdown Voltage | BV _{ECO} | -5 | — | — | V | I _E = -100μA |
| Emitter-Base Breakdown Voltage | BV _{EBO} | -8 | — | — | V | I _E = -100μA |
| Collector Cutoff Current | I _{CBO} | — | — | -100 | nA | V _{CB} = -60V |
| | | — | — | -10 | μA | V _{CB} = -60V, T _A = +125°C |
| Collector Cutoff Current | I _{CES} | — | — | -300 | nA | V _{CB} = -48V |
| Emitter Cutoff Current | I _{EBO} | — | — | -50 | nA | V _{EB} = -7V |
| Collector-Emitter Saturation Voltage (Note 10) | V _{CE(sat)} | — | -55 | — | mV | I _C = -100mA, I _B = -1mA |
| | | — | -90 | -140 | mV | I _C = -1A, I _B = -20mA |
| | | — | -35 | -50 | mV | I _C = -1A, I _B = -100mA |
| | | — | -140 | -190 | mV | I _C = -3.5A, I _B = -175mA |
| | | — | -290 | -550 | mV | I _C = -5A, I _B = -250mA |
| | | — | -170 | -250 | mV | I _C = -6A, I _B = -600mA |
| Base-Emitter Saturation Voltage (Note 10) | V _{BE(sat)} | — | -870 | -1,000 | mV | I _C = -3.5A, I _B = -175mA |
| | | — | -980 | -1,100 | mV | I _C = -6A, I _B = -600mA |
| Base-Emitter Turn-On Voltage (Note 10) | V _{BE(on)} | — | -750 | -850 | mV | I _C = -3.5A, V _{CE} = -2V |
| | | — | -810 | -900 | mV | I _C = -6A, V _{CE} = -2V |
| DC Current Gain (Note 10) | h _{FE} | 250 | 355 | — | — | I _C = -10mA, V _{CE} = -2V |
| | | 300 | 350 | 550 | — | I _C = -100mA, V _{CE} = -2V |
| | | 260 | 315 | — | — | I _C = -1A, V _{CE} = -2V |
| | | 230 | 290 | — | — | I _C = -2A, V _{CE} = -2V |
| | | 190 | 235 | — | — | I _C = -3.5A, V _{CE} = -2V |
| | | 35 | 70 | — | — | I _C = -6A, V _{CE} = -2V |
| Input Capacitance | C _{ibo} | — | 555 | — | pF | V _{EB} = 0.5V, f = 1MHz |
| Output Capacitance | C _{obo} | — | 40 | — | pF | V _{CB} = 10V, f = 1MHz |
| Current Gain-Bandwidth Product | f _T | 100 | 180 | — | MHz | V _{CE} = -10V, I _C = -100mA f = 50MHz |
| Turn-On Time | t _d | — | 13.5 | — | ns | V _{CC} = -10V, I _C = -3.5A I _{B1} = -I _{B2} = -350mA |
| | t _r | — | 65 | — | ns | |
| Turn-Off Time | t _s | — | 205 | — | ns | |
| | t _f | — | 19 | — | ns | |

Note: 10. Measured under pulsed conditions. Pulse width ≤ 300μs. Duty cycle ≤ 2%.

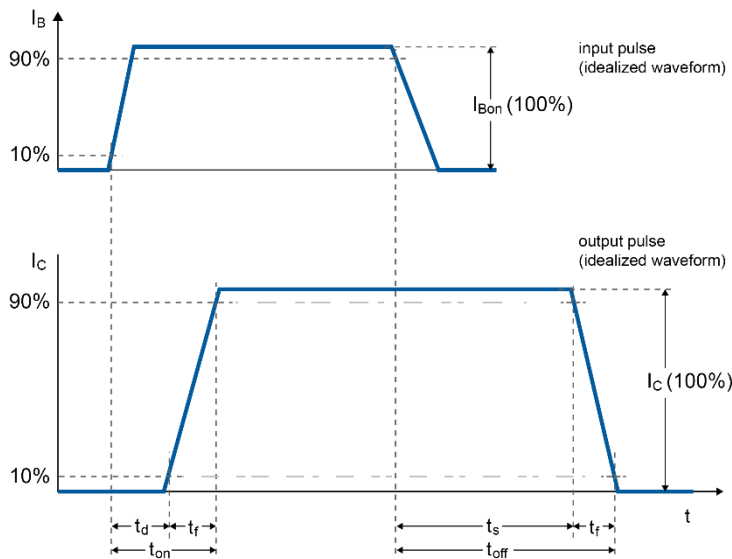


Fig 6. Timing Waveform

Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

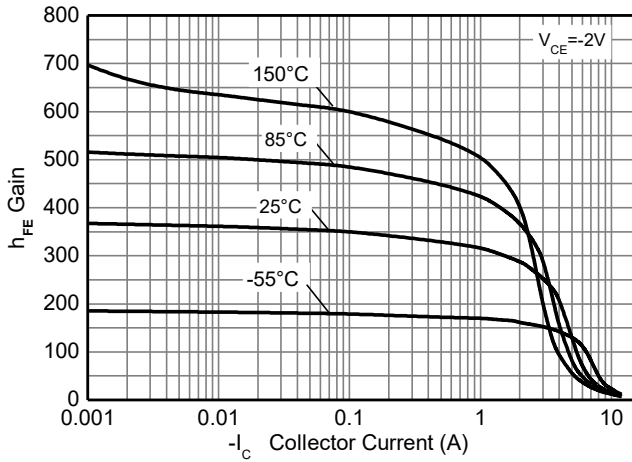


Fig. 7 $h_{FE} \ v \ I_C$

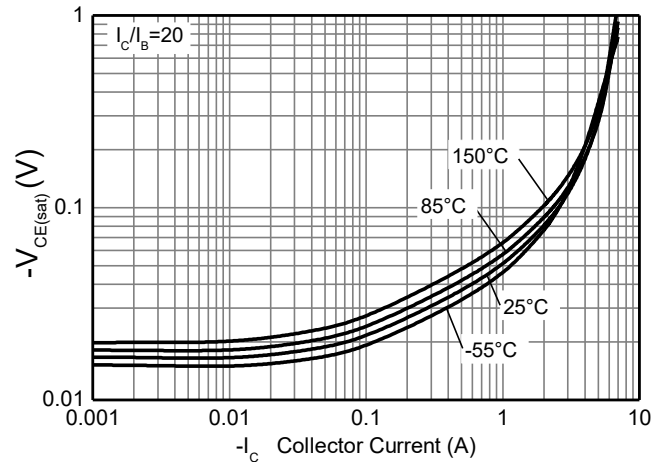


Fig. 8 $V_{CE(sat)} \ v \ I_C$

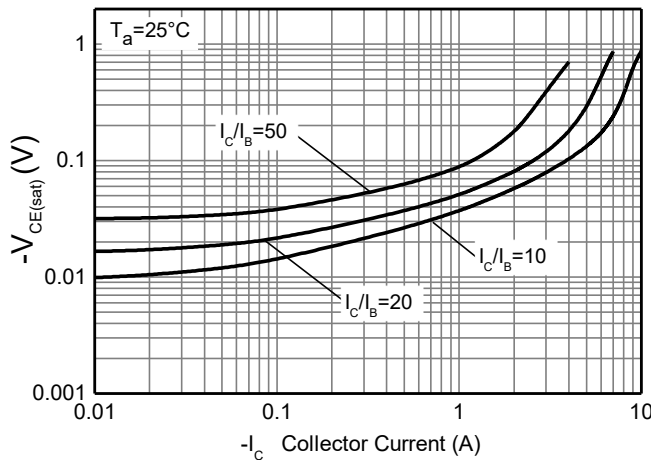


Fig. 9 $V_{CE(sat)} \ v \ I_C$

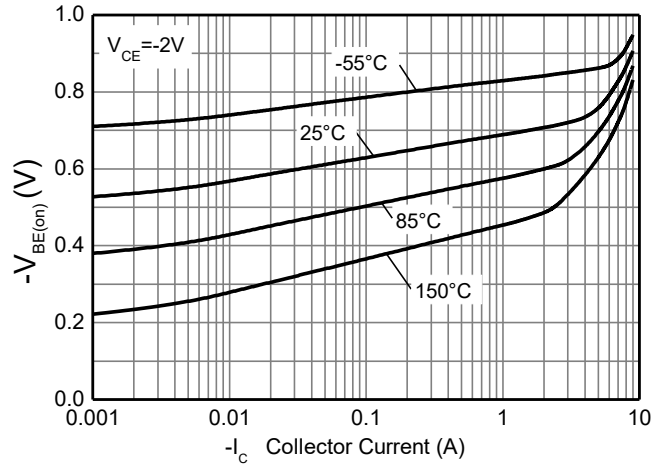


Fig. 10 $V_{BE(on)} \ v \ I_C$

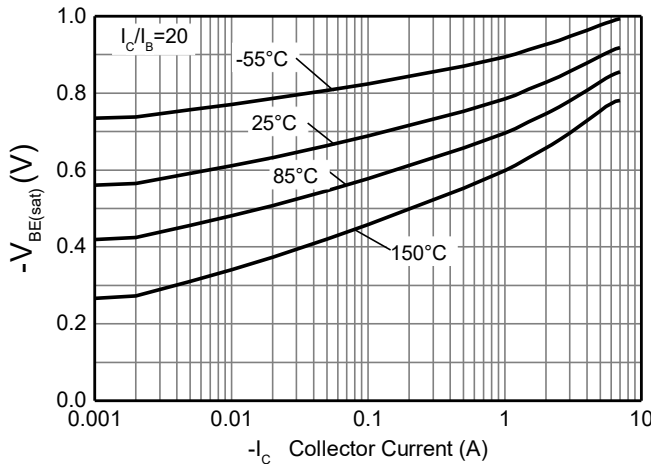


Fig. 11 $V_{BE(sat)} \ v \ I_C$

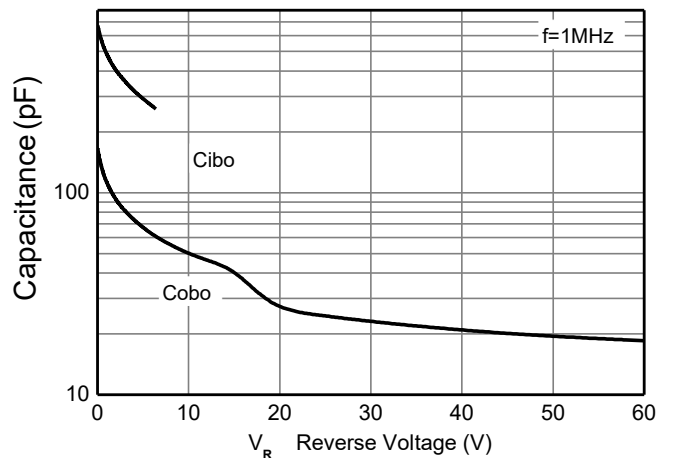


Fig. 12 Typical Junction Capacitance

Typical Electrical Characteristics (continued) (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)

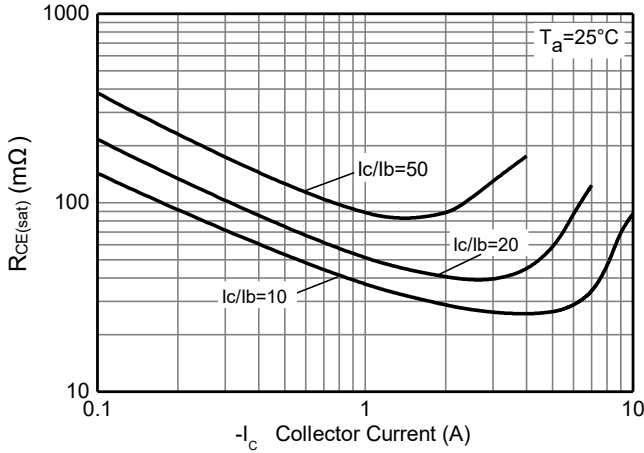


Fig. 13 $R_{CE(sat)} \ v \ I_C$

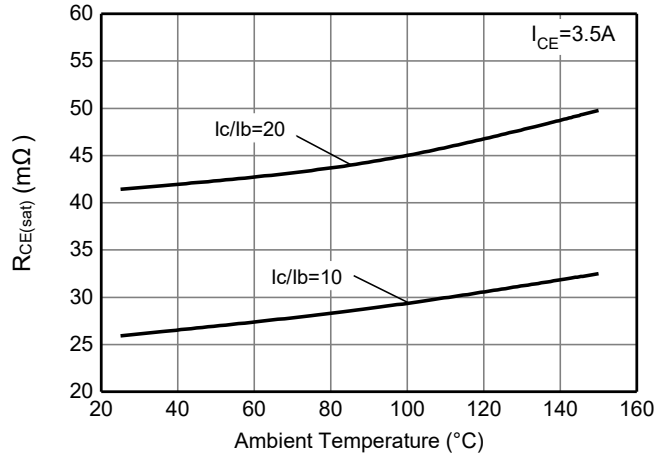


Fig. 14 $R_{CE(sat)} \ v \ T_{amb}$

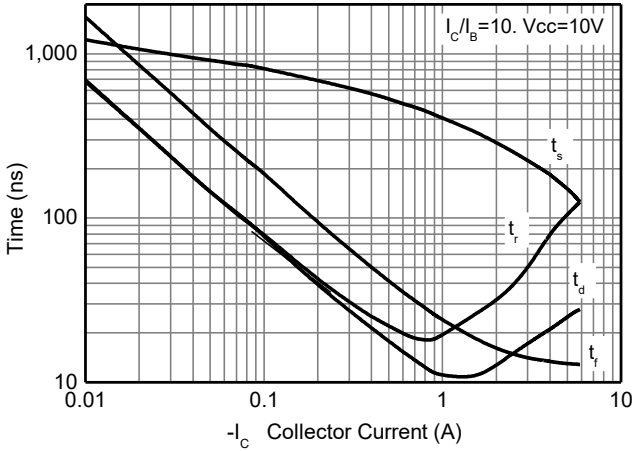
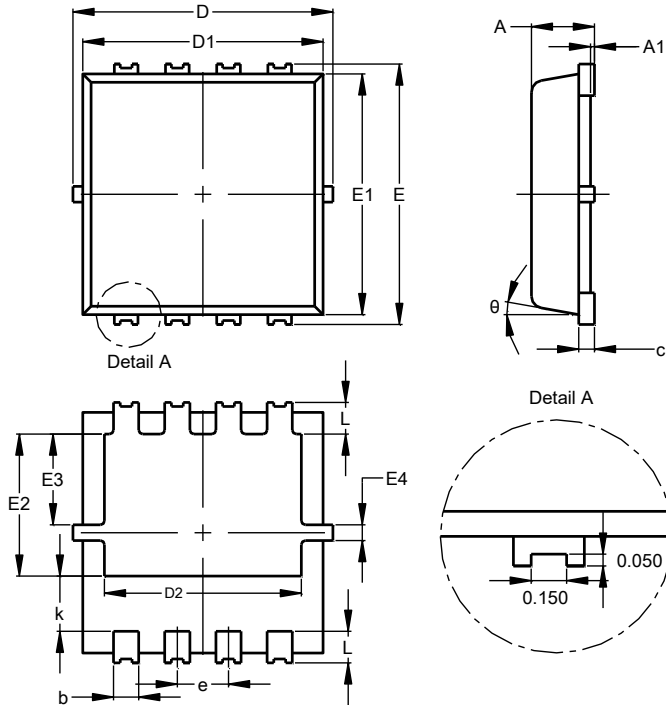


Fig. 15 Switching Performance

Package Outline Dimensions

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

PowerDI3333-8/SWP (Type UX)

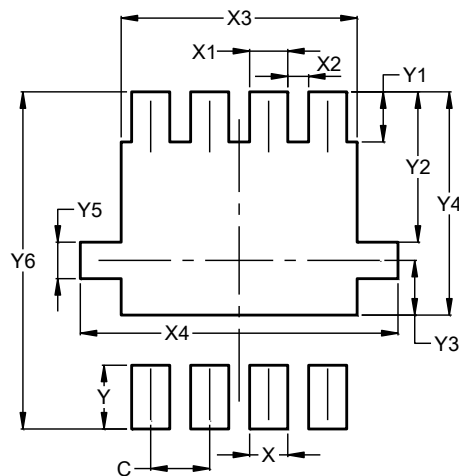


| PowerDI3333-8/SWP (Type UX) | | | |
|-----------------------------|------|------|------|
| Dim | Min | Max | Typ |
| A | 0.75 | 0.85 | 0.80 |
| A1 | 0.00 | 0.05 | -- |
| b | 0.25 | 0.40 | 0.32 |
| c | 0.10 | 0.25 | 0.15 |
| D | 3.20 | 3.40 | 3.30 |
| D1 | 2.95 | 3.15 | 3.05 |
| D2 | 2.30 | 2.70 | 2.50 |
| E | 3.20 | 3.40 | 3.30 |
| E1 | 2.95 | 3.15 | 3.05 |
| E2 | 1.60 | 2.00 | 1.80 |
| E3 | 0.95 | 1.35 | 1.15 |
| E4 | 0.10 | 0.30 | 0.20 |
| e | -- | -- | 0.65 |
| k | 0.50 | 0.90 | 0.70 |
| L | 0.30 | 0.50 | 0.40 |
| θ | 0° | 12° | 10° |
| All Dimensions in mm | | | |

Suggested Pad Layout

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

PowerDI3333-8/SWP (Type UX)



| Dimensions | Value (in mm) |
|------------|---------------|
| C | 0.650 |
| X | 0.420 |
| X1 | 0.420 |
| X2 | 0.230 |
| X3 | 2.600 |
| X4 | 3.500 |
| Y | 0.700 |
| Y1 | 0.550 |
| Y2 | 1.650 |
| Y3 | 0.600 |
| Y4 | 2.450 |
| Y5 | 0.400 |
| Y6 | 3.700 |

Note: 11. Side wall tin plated package for wettable flanks in AOI.

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